

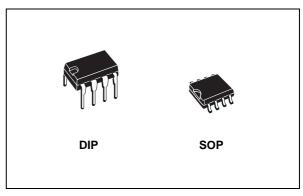


# ±15KV ESD PROTECTED, LOW POWER RS-485/RS-422 TRANSCEIVER

- LOW QUIESCENT CURRENT: 300µA
- DESIGNED FOR RS-485 INTERFACE APPLICATIONS
- -7V TO 12V COMMON MODE INPUT VOLTAGE RANGE
- DRIVER MAINTAINS HIGH IMPEDANCE IN 3-STATE OR WITH THE POWER OFF
- 70mV TYPICAL INPUT HYSTERESIS
- 30ns PROPAGATION DELAYS, 5ns SKEW
- OPERATE FROM A SINGLE 5V SUPPLY
- CURRENT LIMITING AND THERMAL SHUTDOWN FOR DRIVER OVERLOAD PROTECTION
- ESD PROTECTION: ±15KV (H.B.M.) ±8KV (IEC-1000-4-2 CONTACT DISCHARGE)
- ALLOWS UP TO 64 TRANSCEIVERS ON THE BUS

#### **DESCRIPTION**

The ST485E is al low power transceiver for RS-485 and RS-422 communication. Each driver output and receiver input is protected against  $\pm 15 \text{KV}$  electrostatic discharge (H.B.M.) (ESD) shocks, without latcup. These parts contain one



driver and one receiver in half duplex configuration.

This transceiver draw  $300\mu A$  (typ.) of supply current when unloaded or fully loaded with disabled drivers.

It operates from a single 5V supply.

Driver is short-circuit current limited and is protected against excessive power dissipation by thermal shutdown circuitry that place the driver outputs into a high-impedance state.

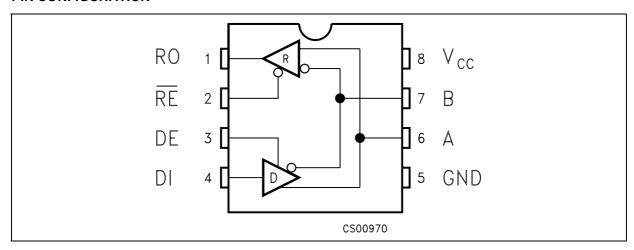
The ST485E is designed for bi-directional data communications on multipoint bus transmission line (half-duplex applications).

#### **ORDERING CODES**

Туре	Temperature Range	Package	Comments
ST485ECN	0 to 70 °C	DIP-8	50parts per tube / 40tube per box
ST485EBN	-40 to 85 °C	DIP-8	50parts per tube / 40tube per box
ST485EXN	-55 to 125 °C	DIP-8	50parts per tube / 40tube per box
ST485ECD	0 to 70 °C	SO-8 (Tube)	100parts per tube / 20tube per box
ST485EBD	-40 to 85 °C	SO-8 (Tube)	100parts per tube / 20tube per box
ST485EXD	-55 to 125 °C	SO-8 (Tube)	100parts per tube / 20tube per box
ST485ECDR	0 to 70 °C	SO-8 (Tape & Reel)	2500 parts per reel
ST485EBDR	-40 to 85 °C	SO-8 (Tape & Reel)	2500 parts per reel
ST485EXDR	-55 to 125 °C	SO-8 (Tape & Reel)	2500 parts per reel

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#### **PIN CONFIGURATION**



#### **PIN DESCRIPTION**

PIN N°	SYMBOL	NAME AND FUNCTION
1	RO	Receiver Output
2	RE	Receiver Output Enable
3	DE	Driver Output Enable
4	DI	Driver Input
5	GND	Ground
6	A	Non-inverting Receiver Input and Non-inverting Driver Output
7	В	Inverting Receiver Input and Inverting Driver Output
8	V <sub>CC</sub>	Supply Voltage

#### **TRUTH TABLE (DRIVER)**

	INPUTS	OUTPUTS		
RE	DE	DI	В	Α
Х	Н	Н	L	Н
Х	Н	L	Н	L
Х	L	Х	Z	Z

X= Don't Care; Z=High Impedance

### **TRUTH TABLE (RECEIVER)**

	INPUTS					
RE	DE	A-B	RO			
L	L	≥ +0.2V	Н			
L	L	≤-0.2V	L			
L	L	INPUTS OPEN	Н			
Н	L	Х	Z			

X= Don't Care; Z=High Impedance

#### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	Supply Voltage	7	V
V <sub>I</sub>	Control Input Voltage (RE, DE)	-0.5 to (V <sub>CC</sub> + 0.5)	V
V <sub>DI</sub>	Driver Input Voltage (DI)	-0.5 to (V <sub>CC</sub> + 0.5)	V
V <sub>DO</sub>	Driver Output Voltage (A, B)	± 14	V
$V_{RI}$	Receiver Input Voltage (A, B)	± 14	V
V <sub>RO</sub>	Receiver Output Voltage (RO)	-0.5 to (V <sub>CC</sub> + 0.5)	V

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.

#### **ESD PERFORMANCE: TRANSMITTER OUTPUTS, RECEIVER INPUTS**

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
ESD	ESD Protection Voltage	Human Body Model	±15			ΚV
ESD	ESD Protection Voltage	IEC-1000-4-2	±8			KV

#### DC ELECTRICAL CHARACTERISTICS

 $(V_{CC}=5V\pm5\%,\,T_A=T_{MIN}\,\,\,to\,\,T_{MAX}\,,\,unless\,otherwise\,specified.\,Typical\,values\,are\,\,referred\,to\,\,T_A=25^{\circ}C)$ (See Note 1)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
V <sub>OD1</sub>	Differential Driver Output (No Load)				5	V
V <sub>OD2</sub>	Differential Driver Output (With Load)	$R_L = 27\Omega \text{ (RS-485) (See Fig. 1)}$ $R_L = 50\Omega \text{ (RS-422) (See Fig. 1)}$	1.5		5 5	V V
ΔV <sub>OD</sub>	Change in Magnitude of Driver Differential Output Voltage for Complementary Output States	$R_L = 27\Omega$ or $50\Omega$ (See Fig. 1)			0.2	V
V <sub>oc</sub>	Driver Common-Mode Output Voltage	$R_L = 27\Omega \text{ or } 50\Omega \text{ (See Fig. 1)}$			3	V
ΔV <sub>OC</sub>	Change in Magnitude of Driver Common-Mode Output Voltage for Complementary Output States	$R_L = 27\Omega$ or $50\Omega$ (See Fig. 1)			0.2	V
V <sub>IH</sub>	Input High Voltage	RE, DE, DI	2.0			V
$V_{IL}$	Input Low Voltage	RE, DE, DI			0.8	V
I <sub>IN1</sub>	Input Current	RE, DE, DI			± 2	μΑ
I <sub>IN2</sub>	Input Current (A, B)	$V_{CM} = 0V$ or 5.25V $V_{DE} = 0V$ $V_{IN} = 12V$ $V_{IN} = -7V$			1 -0.8	mA mA
V <sub>TH</sub>	Receiver Differential Threshold Voltage	V <sub>CM</sub> = -7 to 12V	-0.2		0.2	V
$\Delta V_{TH}$	Receiver Input Hysteresis	V <sub>CM</sub> = 0V		70		mV
V <sub>OH</sub>	Receiver Output High Voltage	$I_O = -4mA$ $V_{ID} = 200mV$	3.5			V
V <sub>OL</sub>	Receiver Output Low Voltage	$I_O = 4mA$ $V_{ID} = -200mV$			0.4	V
I <sub>OZR</sub>	3-State (High Impedance) Output Current at Receiver	$V_{O} = 0.4 \text{ to } 2.4 \text{V}$			± 1	μΑ
R <sub>IN</sub>	Receiver Input Resistance	V <sub>CM</sub> = -7 to 12V	24			KΩ
I <sub>CC</sub>	No Load Supply Current (Note 2)	$V_{RE} = 0V \text{ or } V_{CC}$ $V_{DE} = V_{CC}$ $V_{DE} = 0V$		400 300	900 500	μ <b>Α</b> μ <b>Α</b>
I <sub>OSD1</sub>	Driver Short-Circuit Current, V <sub>O</sub> =High	V <sub>O</sub> = -7 to 12V (Note 3)	35		250	mA
I <sub>OSD2</sub>	Driver Short-Circuit Current, V <sub>O</sub> =Low	$V_O = -7$ to 12V (Note 3)	35		250	mA
I <sub>OSR</sub>	Receiver Short-Circuit Current	$V_{O} = 0V$ to $V_{CC}$	7		95	mA

Note 1: All currents into device pins are positive; all cuttents out of device pins are negative; all voltages are referenced to device ground



Note 2: Supply current specification is valid for loaded transmitters when  $V_{\text{DE}} = 0V$  Note 3: Applies to peak current. See typical Operating Characteristics.

#### **DRIVER SWITCHING CHARACTERISTICS**

(V<sub>CC</sub> = 5V  $\pm$ 5%, T<sub>A</sub> = T<sub>MIN</sub> to T<sub>MAX</sub>, unless otherwise specified. Typical values are referred to T<sub>A</sub> = 25°C) (See Note 1)

Symbol	Parameter	Test 0	Conditions	Min.	Тур.	Max.	Unit
t <sub>PLH</sub>	Propagation Delay Input to	$R_{DIFF} = 54\Omega$	$C_{L1} = C_{L2} = 100pF$		25	45	ns
t <sub>PHL</sub>	Output	(See Fig. 3 and 5)					
t <sub>SK</sub>	Output Skew to Output	$R_{DIFF} = 54\Omega$	$C_{L1} = C_{L2} = 100pF$		2	5	ns
		(See Fig. 3 and 5)					
t <sub>TLH</sub>	Rise or Fall Time	$R_{DIFF} = 54\Omega$	$C_{L1} = C_{L2} = 100pF$		15	40	ns
$t_{THL}$		(See Fig. 3 and 5)					
t <sub>PZH</sub>	Output Enable Time	C <sub>L</sub> = 100pF	S2 = Closed		35	50	ns
		(See Fig. 4 and 6)					
t <sub>PZL</sub>	Output Enable Time	C <sub>L</sub> = 100pF	S1 = Closed		25	40	ns
		(See Fig. 4 and 6)					
t <sub>PLZ</sub>	Output Disable Time	C <sub>L</sub> = 15pF	S1 = Closed		25	40	ns
		(See Fig. 4 and 6)					
t <sub>PHZ</sub>	Output Disable Time	C <sub>L</sub> = 15pF	S2 = Closed		35	50	ns
		(See Fig. 4 and 6)					

Note 1: All currents into device pins are positive; all cuttents out of device pins are negative; all voltages are referenced to device ground unless specified.

#### RECEIVER SWITCHING CHARACTERISTICS

( $V_{CC}$  = 5V ±5%,  $T_A$  =  $T_{MIN}$  to  $T_{MAX}$ , unless otherwise specified. Typical values are referred to  $T_A$  = 25°C) (See Note 1)

Symbol	Parameter	Test C	Conditions	Min.	Тур.	Max.	Unit
t <sub>PLH</sub>	Propagation Delay Input to Output	$R_{DIFF} = 54\Omega$ (See Fig. 3 and 7)	$C_{L1} = C_{L2} = 100pF$		110	130	ns
t <sub>SKD</sub>	Differential Receiver Skew	$R_{DIFF} = 54\Omega$ (See Fig. 3 and 7)	$C_{L1} = C_{L2} = 100pF$		5	10	ns
t <sub>PZH</sub>	Output Enable Time	C <sub>RL</sub> = 15pF (See Fig. 2 and 8)	S2 = Closed		11	35	ns
t <sub>PZL</sub>	Output Enable Time	C <sub>RL</sub> = 15pF (See Fig. 2 and 8)	S1 = Closed		13	35	ns
t <sub>PLZ</sub>	Output Disable Time	C <sub>RL</sub> = 15pF (See Fig. 2 and 8)	S1 = Closed		13	35	ns
t <sub>PHZ</sub>	Output Disable Time	C <sub>RL</sub> = 15pF (See Fig. 2 and 8)	S2 = Closed		11	35	ns
f <sub>MAX</sub>	Maximum Data Rate			5			Mbps

Note 1: All currents into device pins are positive; all cuttents out of device pins are negative; all voltages are referenced to device ground unless specified.

#### **TEST CIRCUITS AND TYPICAL CHARACTERISTICS**

Figure 1 : Driver DC Test Load

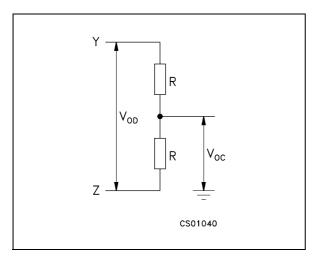


Figure 2: Receiver Timing Test Load

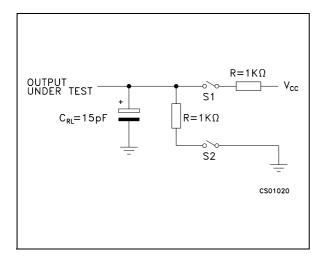


Figure 3 : Drive/Receiver Timing Test Circuit

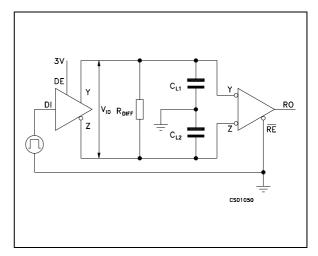


Figure 4 : Driver Timing Test Load

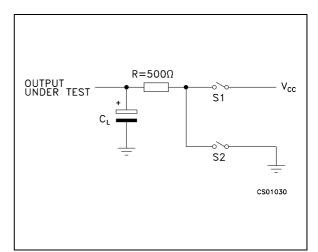


Figure 5 : Driver Propagation Delay

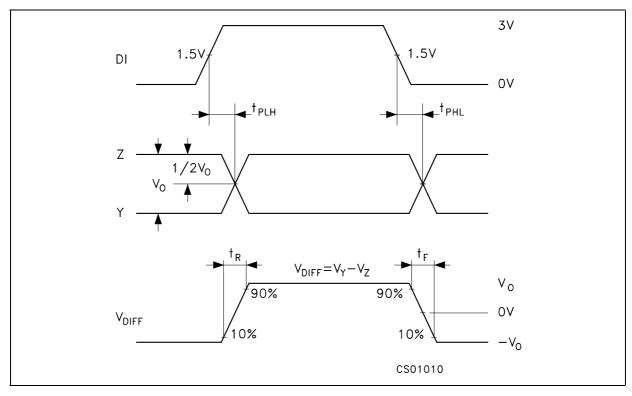


Figure 6: Driver Enable and Disable Time

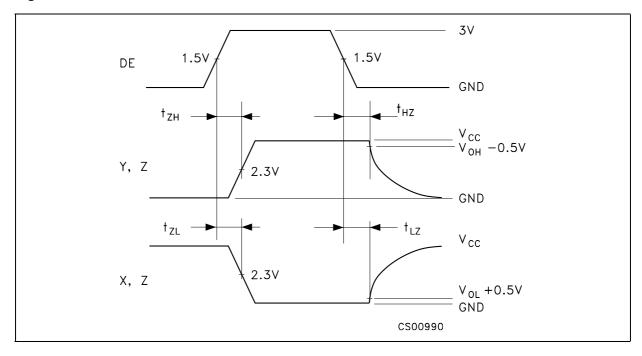


Figure 7: Receiver Propagation Delay

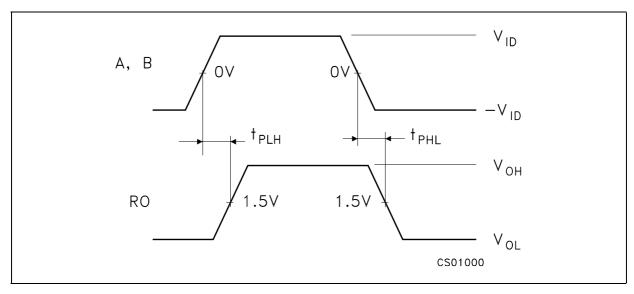
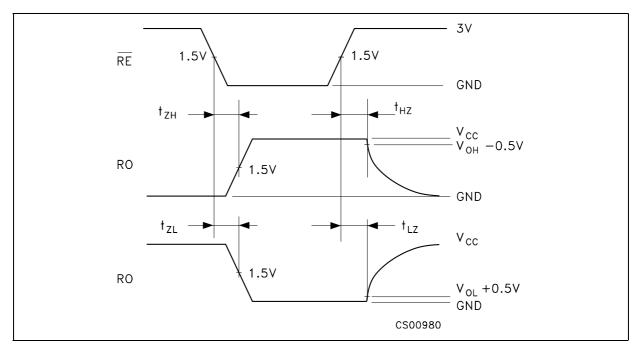
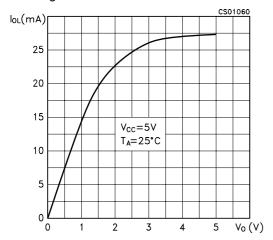


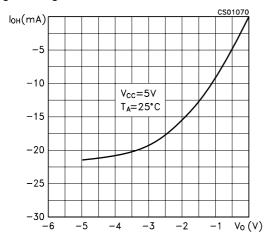
Figure 8: Receiver Enable and Disable Time



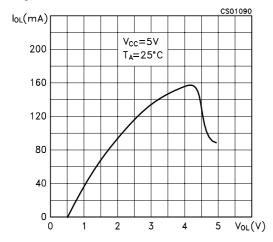
**Figure 9 :** Receiver Output Current vs Output Low Voltage



**Figure 10 :** Receiver Output Current vs Output High Voltage



**Figure 11 :** Driver Output Current vs Output Low Voltage



**Figure 12 :** Driver Output Current vs Output High Voltage

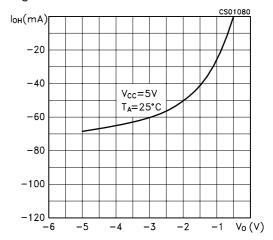
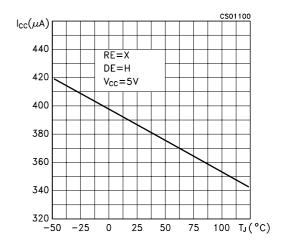
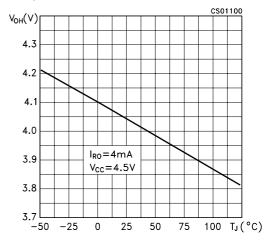


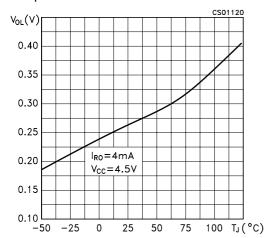
Figure 13 : Supply Current vs Temperature



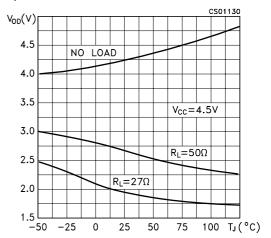
**Figure 14 :** Receiver High Level Output Voltage vs Temperature



**Figure 15 :** Receiver Low Level Output Voltage vs Temperature

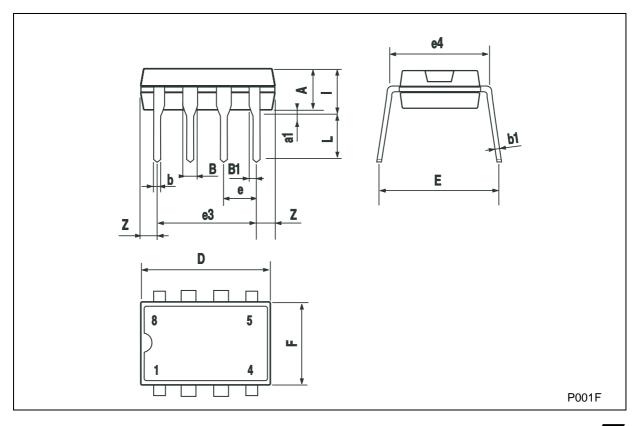


**Figure 16 :** Differential Driver Output Voltage vs Temperature



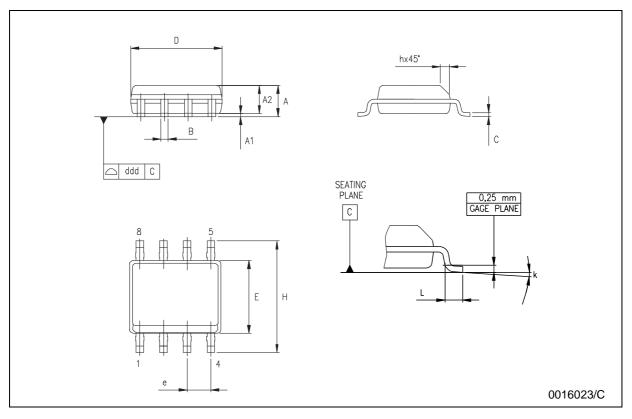
# **Plastic DIP-8 MECHANICAL DATA**

DIM.		mm.			inch			
DIWI.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.		
Α		3.3			0.130			
a1	0.7			0.028				
В	1.39		1.65	0.055		0.065		
B1	0.91		1.04	0.036		0.041		
b		0.5			0.020			
b1	0.38		0.5	0.015		0.020		
D			9.8			0.386		
Е		8.8			0.346			
е		2.54			0.100			
e3		7.62			0.300			
e4		7.62			0.300			
F			7.1			0.280		
I			4.8			0.189		
L		3.3			0.130			
Z	0.44		1.6	0.017		0.063		

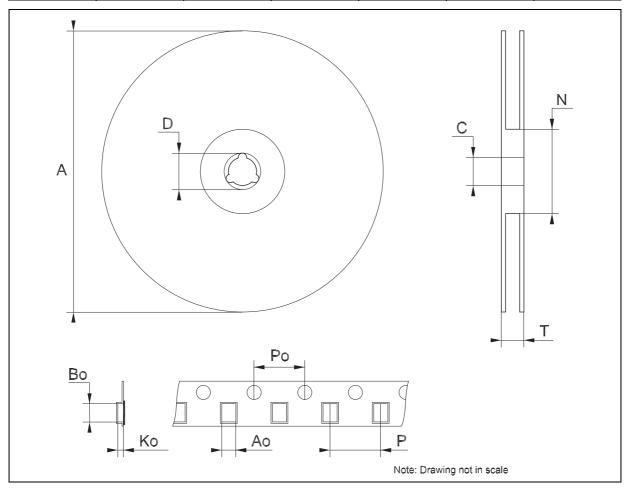


# **SO-8 MECHANICAL DATA**

DIM		mm.			inch			
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.		
А	1.35		1.75	0.053		0.069		
A1	0.10		0.25	0.04		0.010		
A2	1.10		1.65	0.043		0.065		
В	0.33		0.51	0.013		0.020		
С	0.19		0.25	0.007		0.010		
D	4.80		5.00	0.189		0.197		
E	3.80		4.00	0.150		0.157		
е		1.27			0.050			
Н	5.80		6.20	0.228		0.244		
h	0.25		0.50	0.010		0.020		
L	0.40		1.27	0.016		0.050		
k		-	8° (I	max.)				
ddd			0.1			0.04		



DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
А			330			12.992
С	12.8		13.2	0.504		0.519
D	20.2			0.795		
N	60			2.362		
Т			22.4			0.882
Ao	8.1		8.5	0.319		0.335
Во	5.5		5.9	0.216		0.232
Ko	2.1		2.3	0.082		0.090
Ро	3.9		4.1	0.153		0.161
Р	7.9		8.1	0.311		0.319



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